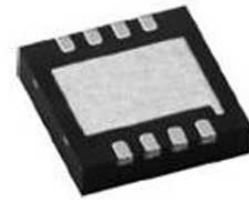


20 V, 7.0 A, Low VCE (sat) PNP Transistor (20V, 7.0A, Low VCE (sat) PNP Transistor), Bipolar Transistors 20V PNP LOW VCE(SAT) XTR

Manufacturers	ON Semiconductor, LLC
Package/Case	WDFN-3
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for NSS20500UW3T2G or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.



General Description

Low VCE(sat) Bipolar Transistors are miniature surface mount devices featuring ultra low saturation voltage VCE(sat) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Features

High Current, Low VCEsat, ESD Robust, High Current Gain, High Cut Off Frequency, Low Profile Package, Linear Gain (Beta)

Improved Circuit Efficiency, Decreased Battery Charge Time, Reduce component count, High Frequency Switching, Smaller Portable Product, No distortion

Application

ONSEMI

Related Products



[NSS1C200LT1G](#)

ON Semiconductor, LLC
SOT-23-3



[NTNS3164NZT5G](#)

ON Semiconductor, LLC
XDFN3-3



[NSVBC114YPDXV65G](#)

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[NSVBC857BTT1G](#)

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[NSVUMC5NT2G](#)

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SC-88A / SC-70-5



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